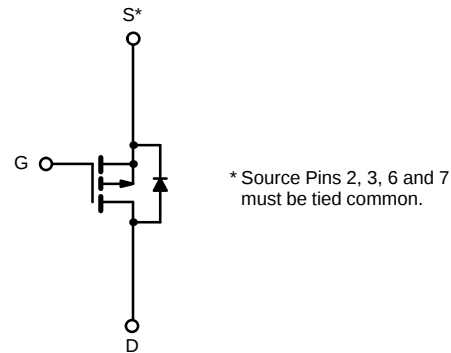
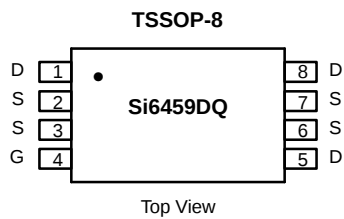




P-Channel 60-V (D-S) MOSFET

TrenchFET®
Power MOSFETs

PRODUCT SUMMARY		
V_{DS} (V)	$r_{DS(on)}$ (Ω)	I_D (A)
-60	0.120 @ $V_{GS} = -10$ V	± 2.6
	0.150 @ $V_{GS} = -4.5$ V	± 2.4



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)				
Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V_{DS}	-60	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current ($T_J = 150^\circ\text{C}$) ^a	$T_A = 25^\circ\text{C}$	I_D	± 2.6	A
	$T_A = 70^\circ\text{C}$		± 2.1	
Pulsed Drain Current		I_{DM}	± 30	
Continuous Source Current (Diode Conduction) ^a		I_S	-1.25	
Maximum Power Dissipation ^a	$T_A = 25^\circ\text{C}$	P_D	1.5	W
	$T_A = 70^\circ\text{C}$		1.0	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55 to 150	$^\circ\text{C}$

THERMAL RESISTANCE RATINGS			
Parameter	Symbol	Limit	Unit
Maximum Junction-to-Ambient ^a	R_{thJA}	83	$^\circ\text{C/W}$

Notes

a. Surface Mounted on FR4 Board, $t \leq 10$ sec.

For SPICE model information via the Worldwide Web: <http://www.vishay.com/www/product/spice.htm>

SPECIFICATIONS ($T_J = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

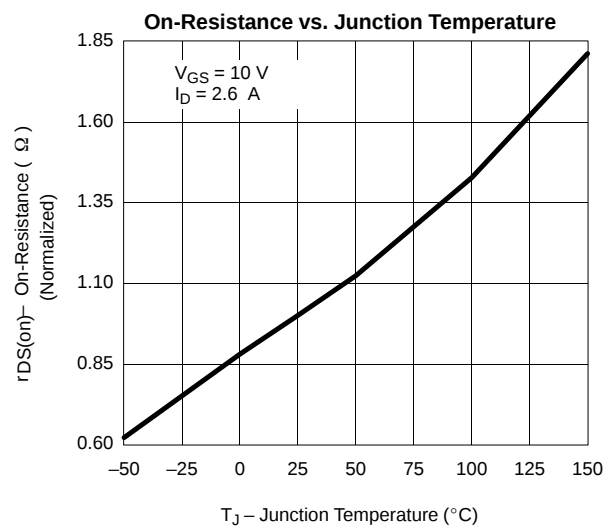
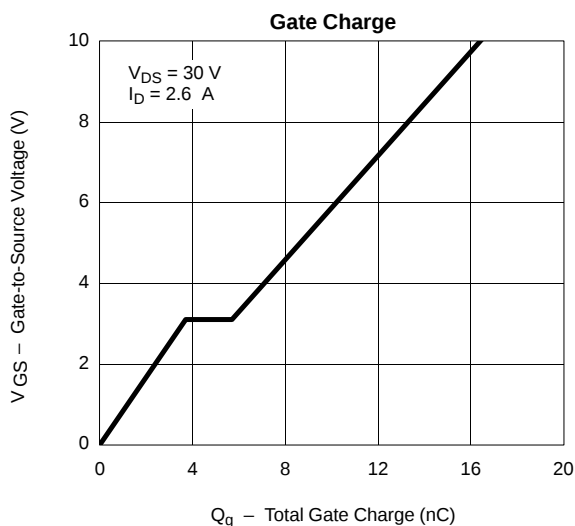
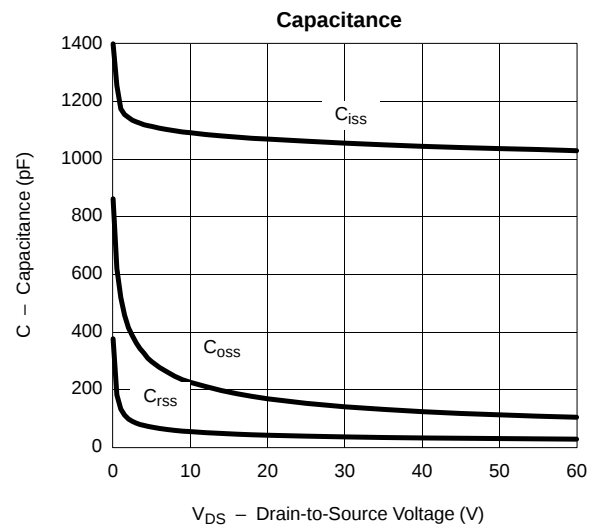
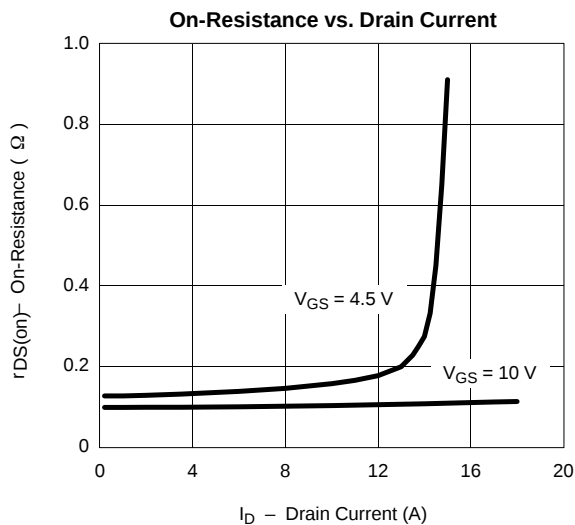
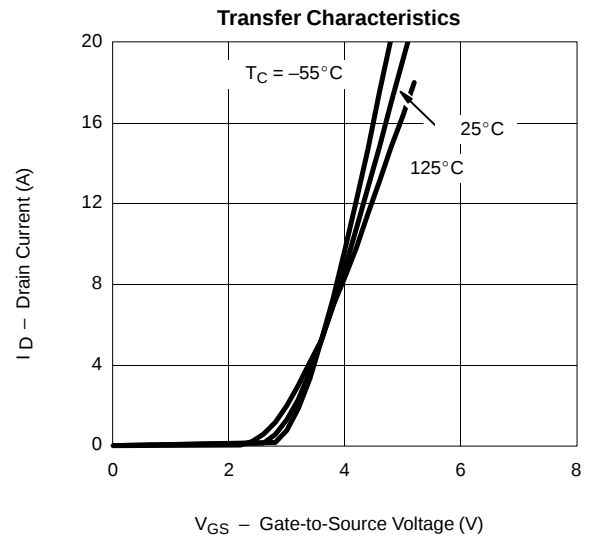
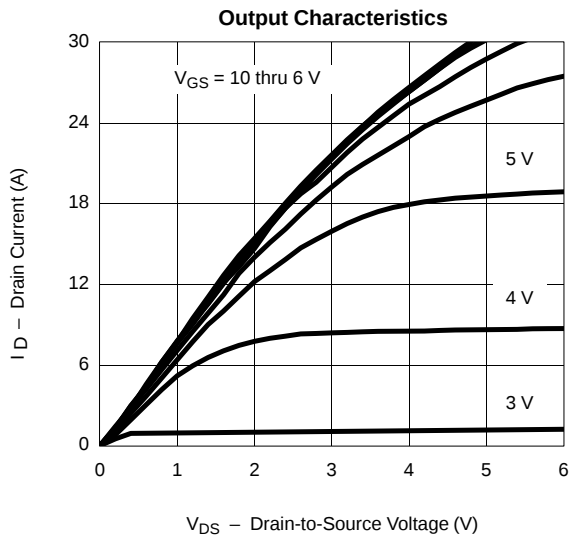
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Static						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = -250\ \mu\text{A}$	-1.0			V
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0\ \text{V}$, $V_{GS} = \pm 20\ \text{V}$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -60\ \text{V}$, $V_{GS} = 0\ \text{V}$			-1	μA
		$V_{DS} = -60\ \text{V}$, $V_{GS} = 0\ \text{V}$, $T_J = 70^\circ\text{C}$			-25	
On-State Drain Current ^a	$I_{D(on)}$	$V_{DS} = -5\ \text{V}$, $V_{GS} = -10\ \text{V}$	-20			A
Drain-Source On-State Resistance ^a	$r_{DS(on)}$	$V_{GS} = -10\ \text{V}$, $I_D = -2.6\ \text{A}$		0.100	0.120	Ω
		$V_{GS} = -4.5\ \text{V}$, $I_D = -2.4\ \text{A}$		0.125	0.150	
Forward Transconductance ^a	g_{fs}	$V_{DS} = -15\ \text{V}$, $I_D = -2.6\ \text{A}$		7.5		S
Diode Forward Voltage ^a	V_{SD}	$I_S = -1.25\ \text{A}$, $V_{GS} = 0\ \text{V}$		-0.8	-1.2	V
Dynamic^b						
Total Gate Charge	Q_g	$V_{DS} = -30\ \text{V}$, $V_{GS} = -10\ \text{V}$, $I_D = -2.6\ \text{A}$		16	25	nC
Gate-Source Charge	Q_{gs}			3.7		
Gate-Drain Charge	Q_{gd}			2.0		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = -30\ \text{V}$, $R_L = 30\ \Omega$ $I_D \cong -1\ \text{A}$, $V_{GEN} = -10\ \text{V}$, $R_G = 6\ \Omega$		8	15	ns
Rise Time	t_r			10	20	
Turn-Off Delay Time	$t_{d(off)}$			35	50	
Fall Time	t_f			12	25	
Source-Drain Reverse Recovery Time	t_{rr}	$I_F = -1.25\ \text{A}$, $di/dt = 100\ \text{A}/\mu\text{s}$		60	90	

Notes

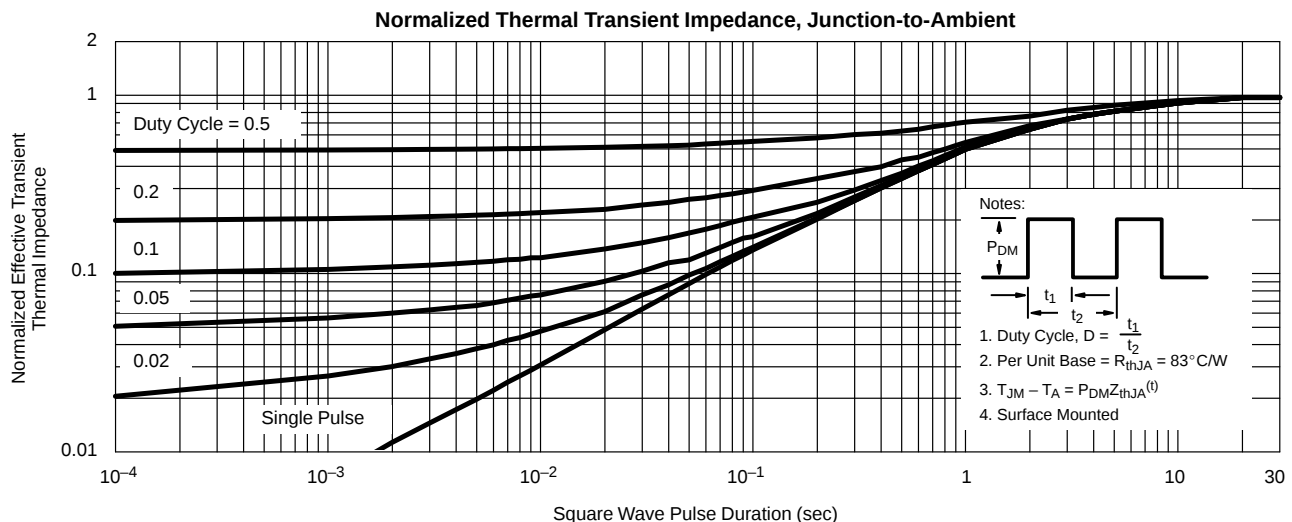
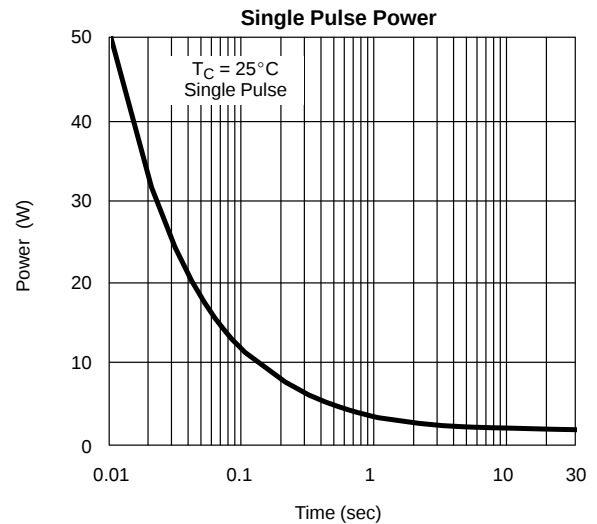
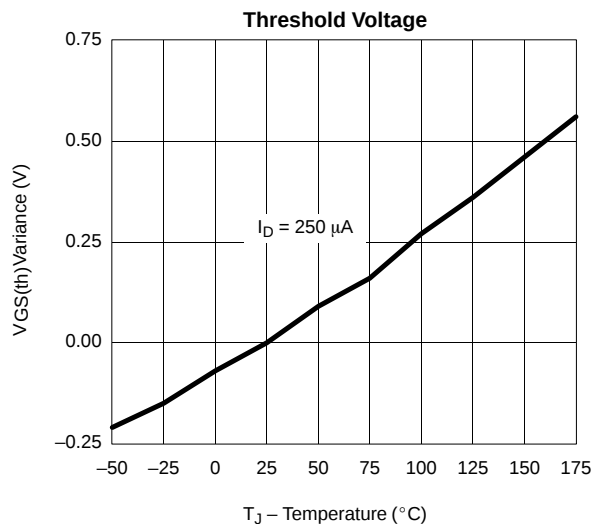
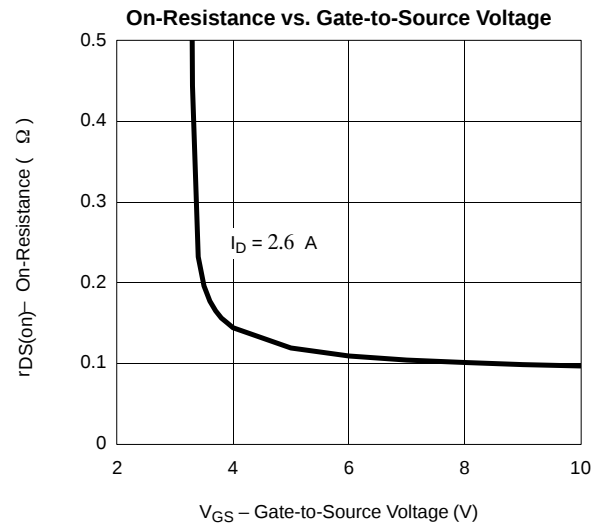
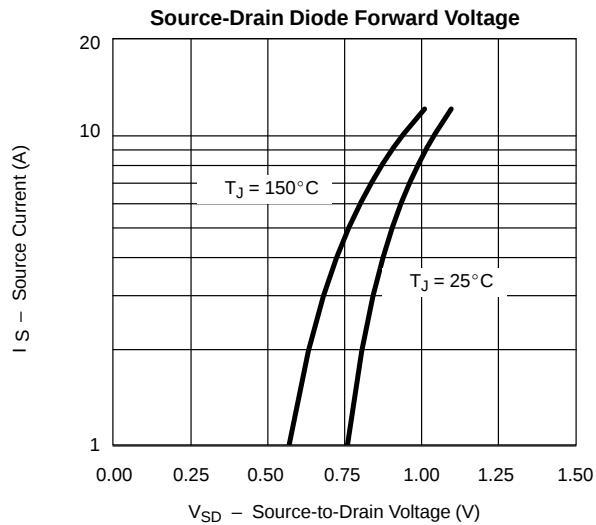
- a. Pulse test; pulse width $\leq 300\ \mu\text{s}$, duty cycle $\leq 2\%$.
b. Guaranteed by design, not subject to production testing.



TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)





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